EV100L-N-00A

Offline Inductor-Less Regulator EV Board

The Future of Analog IC Technology

DESCRIPTION

The MP100L is a compact, inductor-less, good-efficiency, off-line regulator. It steps down the AC line voltage to an adjustable DC output. It is a simple solution to provide a bias voltage to ICs in off-line applications. Its integrated smart-control system uses AC line power only when necessary, thus minimizing device losses to achieve good efficiency. This device can help system designs meet new standby power specifications.

The MP100L provides various protections, such as Thermal Shutdown (TSD), VD Over Voltage Protection (OVP), VD Shrot to GND Protection, Over Load Protection (OLP), Short Circuit Protection (SCP).

The MP100L is available in SOIC8E package.

ELECTRICAL SPECIFICATION

Parameter	Symbol	Value	Units
Supply Voltage	V_{IN}	85~265	VAC
Output Voltage	V_{OUT}	12	V
Output Current	I_{OUT}	20	mA

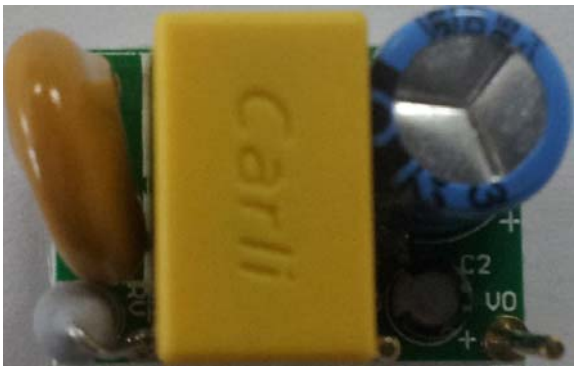
FEATURES

- Universal AC Input (85VAC-to-305VAC)
- Inductor-Less
- Less than 100mW Standby Power
- Excellent EMI
- Low BOM Cost
- Smart Control to Maximum Efficiency
- Adjustable Output Voltage from 1.5V to 15V
- Good Line and Load Regulation
- Thermal Shutdown Protection
- Short-Circuit Protection
- Provide Power-Good Signal

APPLICATIONS

- Wall Switches and Dimmers
- Z-Wave Device and ZigBee Device for Home Automation
- Standby Power for General Off-line Applications

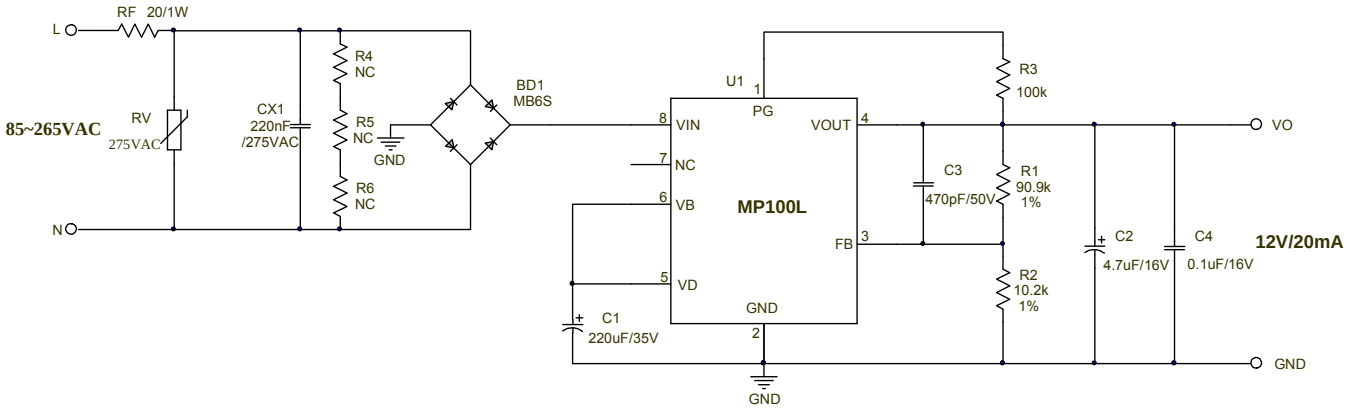
EV100L-N-00A EVALUATION BOARD



(L x W x H) 21mm x 14mm x 20mm

Board Number	MPS IC Number
EV100L-N-00A	MP100GN

EVALUATION BOARD SCHEMATIC



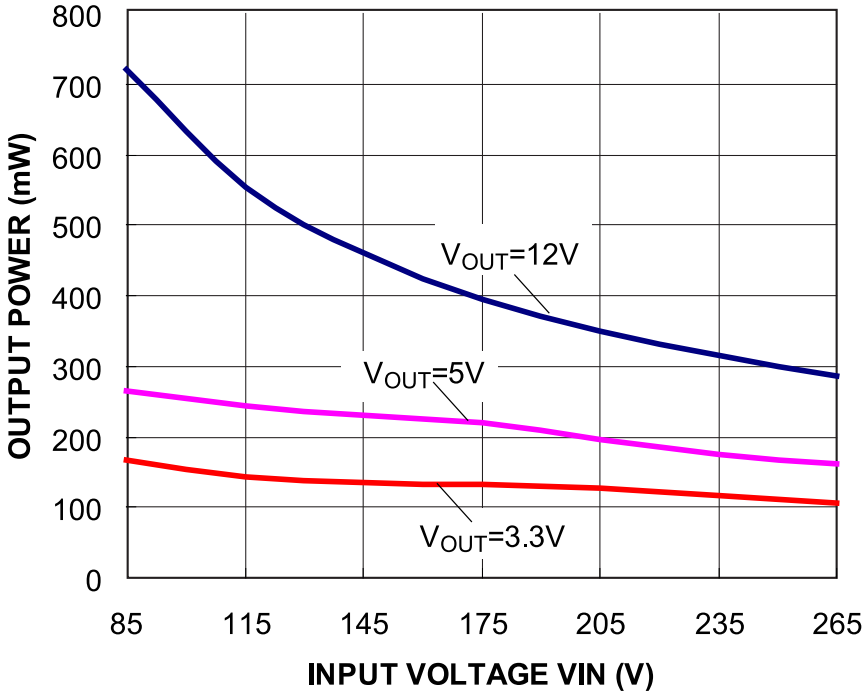
VOUT can be adjusted by choosing the value of R1 and R2, the relationship of them is:

$$VOUT=1.235V*(1+R1/R2)$$

For example, to get 5V output voltage, we can choose, R4=10.2k, R5=30.9k.

The maximum output power of MP100L Vs input voltage is depicted by following chart for 12V, 5V and 3.3V output applications respectively.

The test condition is: in open frame, full bridge rectifier,ambient temperature is 25 °C, the temperature rise of MP100L is less than 60 °C on the test board.



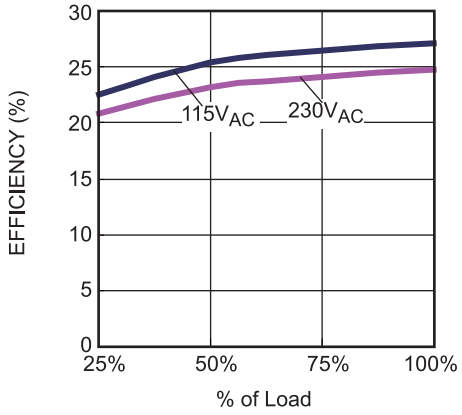
EV100L-N-00A BILL OF MATERIAL

Qty	Ref	Value	Description	Package	Manufacture	Manufacturer_PN
1	BD1	MB6S	Diode;600V;0.5A;	SOIC-4	TaiWan Semiconductor	MB6S
1	C1	220uF	Electrolytic Capacitor;35V;	DIP	Jianghai	CD110-35V220
1	C2	4.7uF	Electrolytic Capacitor;16V;	DIP	Nichicon	UMA1C4R7MCD2
1	C3	470pF	Ceramic Capacitor; 50V;C0G;	0603	Murata	GRM1885C1H471JA01D
1	C4	100nF	Ceramic Capacitor; 16V;X7R;	0603	Murata	GRM188R71C104KA01D
1	CX1	220nF	Film Capacitor; 275V;10%	DIP	Kaili	PX24K3IC59L270D9R
1	R1	90.9kΩ	Film Resistor;1%;	0603	Yageo	RC0603FR-0790K9L
1	R2	10.2kΩ	Film Resistor;1%;	0603	Yageo	RC0603FR-0710K2L
1	R3	100kΩ	Film Resistor;1%;	0603	Yageo	RC0603FR-07100KL
1	RF	20Ω	Fuse Resistor; 5%;1W	DIP	Great Electronics	1WSJT-52-20R
1	RV	275Vac	TVR10431KSY, 430V(1 mA);	DIP	TKS	TVR10431KSY
1	U1	MP100L	Offline Regulator	SOIC8E	MPS	MP100LGN R1

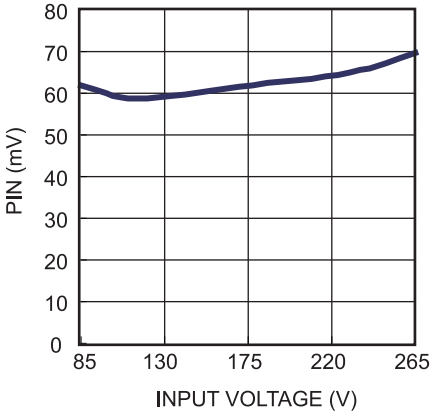
EVB TEST RESULTS

Performance waveforms are tested on the evaluation board.
V_{OUT} = 12V, I_{OUT} = 20mA, T_A = 25ºC, unless otherwise noted.

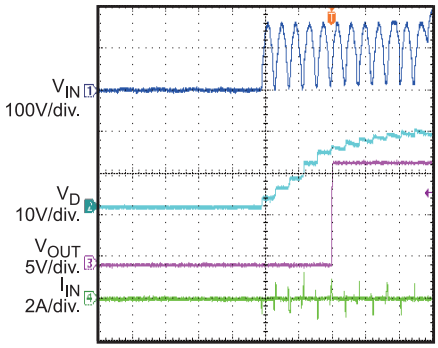
Efficiency vs. Load



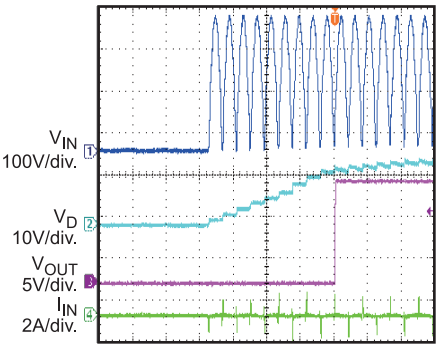
No Load Power vs. Input Voltage



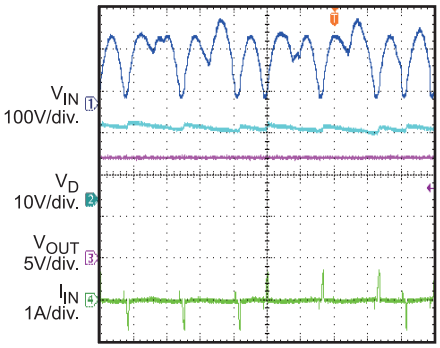
Input Power Start Up
V_{IN} = 115V_{AC}



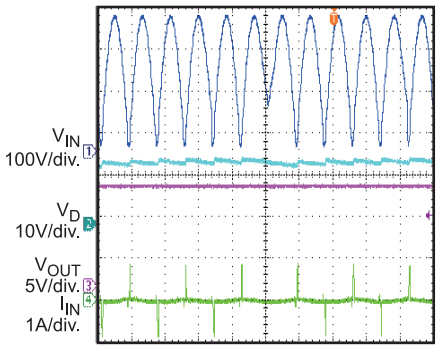
Input Power Start Up
V_{IN} = 230V_{AC}



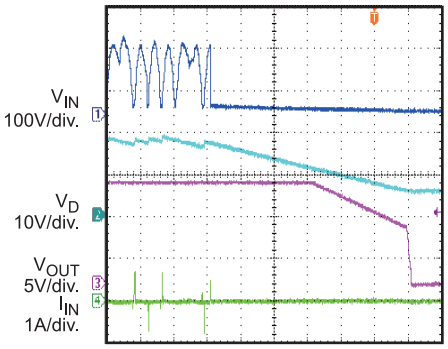
Steady State
V_{IN} = 115V_{AC}



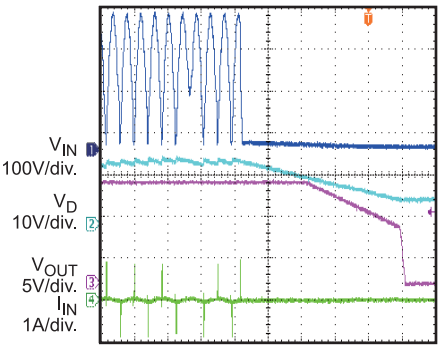
Steady State
V_{IN} = 230V_{AC}



Input Power Shut Down
V_{IN} = 115V_{AC}



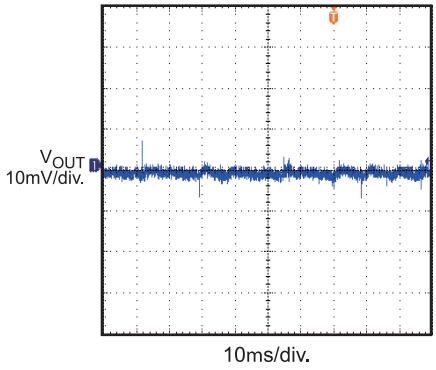
Input Power Shut Down
V_{IN} = 230V_{AC}



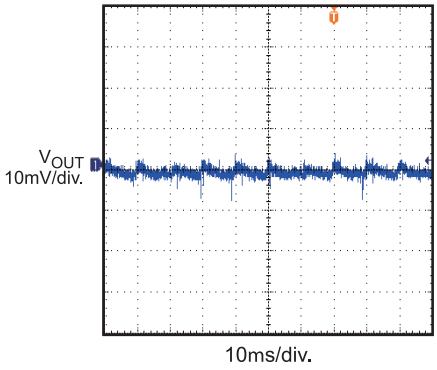
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{OUT} = 12V, I_{OUT} = 20mA, T_A = 25ºC, unless otherwise noted.

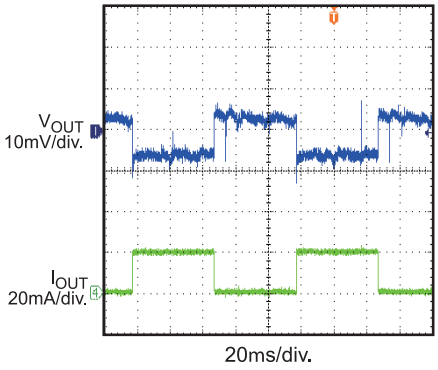
Output Ripple
V_{IN} = 115V_{AC}



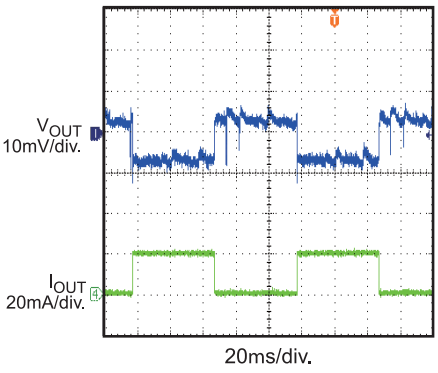
Output Ripple
V_{IN} = 230V_{AC}



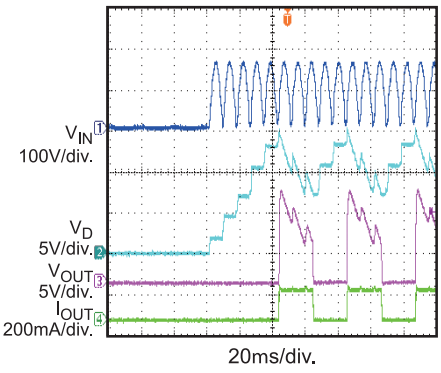
Load Transient
V_{IN} = 115V_{AC}, 0 to 20mA



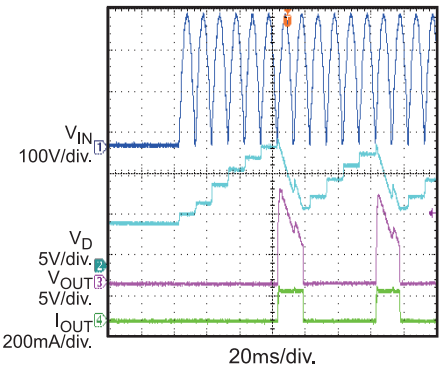
Load Transient
V_{IN} = 230V_{AC}, 0 to 20mA



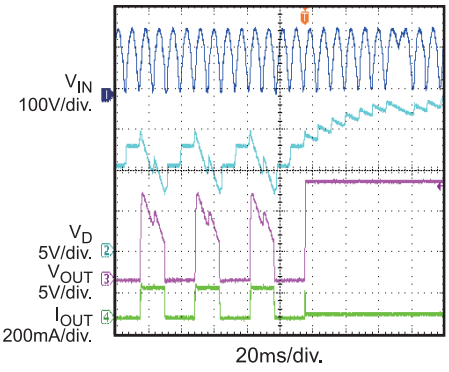
Over Load Protection Entry
V_{IN} = 115V_{AC}



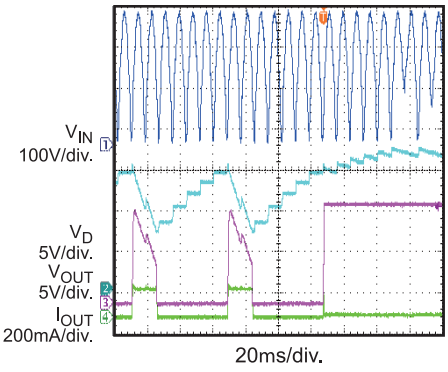
Over Load Protection Entry
V_{IN} = 230V_{AC}



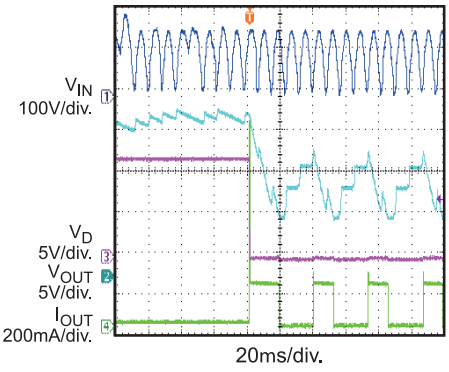
Over Load Protection Recovery
V_{IN} = 115V_{AC}



Over Load Protection Recovery
V_{IN} = 230V_{AC}



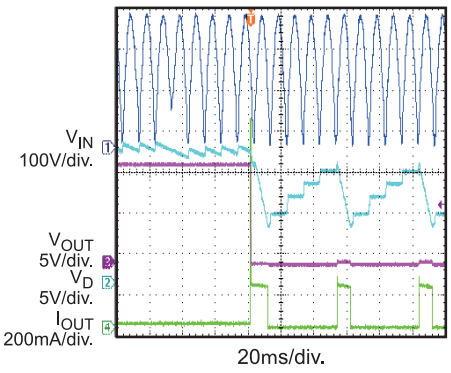
Shrot Circuit Protection Entry
V_{IN} = 115V_{AC}



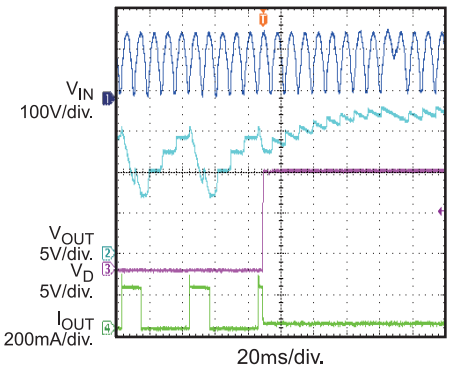
EVB TEST RESULTS *(continued)*

Performance waveforms are tested on the evaluation board.
V_{OUT} = 12V, I_{OUT} = 20mA, T_A = 25ºC, unless otherwise noted.

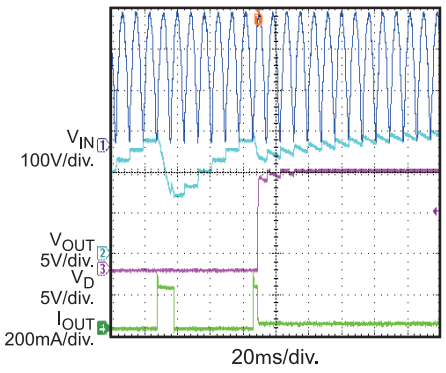
Short Circuit Protection Entry
V_{IN} = 230V_{AC}



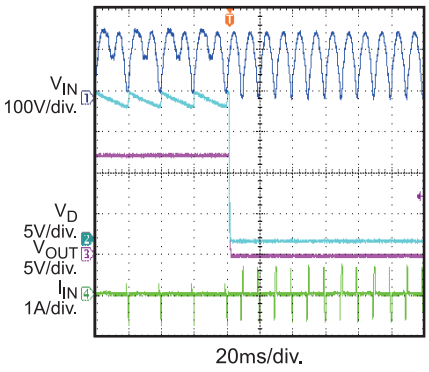
Short Circuit Protection Entry
V_{IN} =115V_{AC}



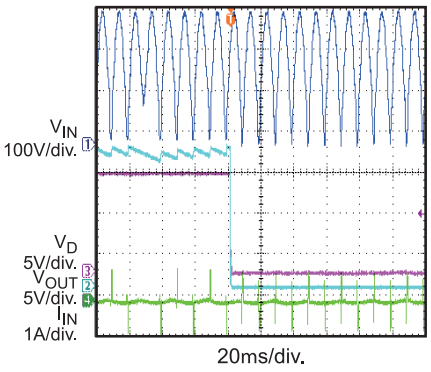
Short Circuit Protection Recovery
V_{IN} = 230V_{AC}



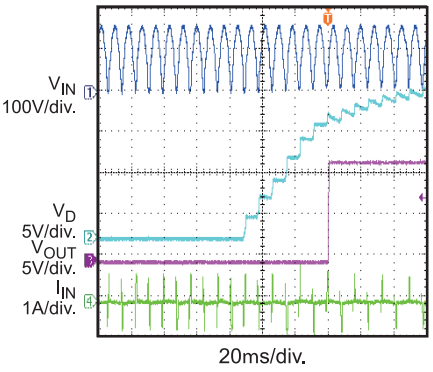
VB Short to GND Protection Entry
V_{IN} =115V_{AC}



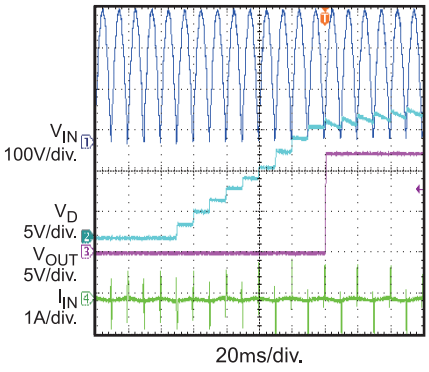
VB Short to GND Protection Entry
V_{IN} = 230V_{AC}



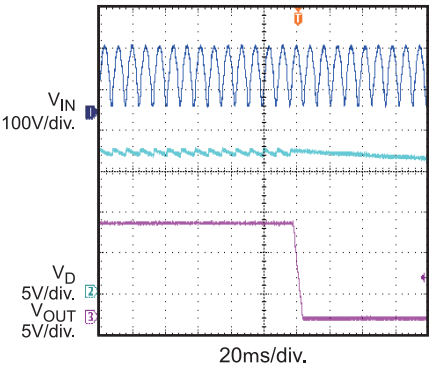
VB Short to GND Protection Recovery
V_{IN} =115V_{AC}



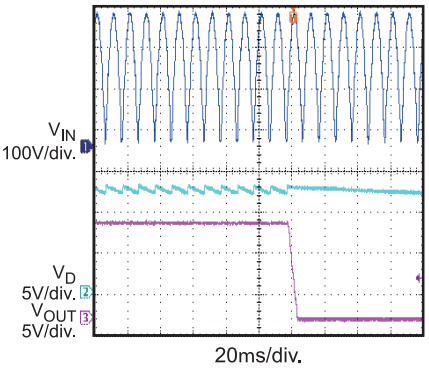
VB Short to GND Protection Recovery
V_{IN} =230V_{AC}



Thermal Shutdown Protection Entry
V_{IN} =115V_{AC}



Thermal Shutdown Protection Entry
V_{IN} =230V_{AC}



EVB TEST RESULTS *(continued)*

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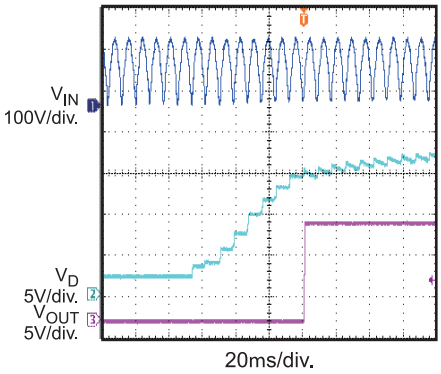
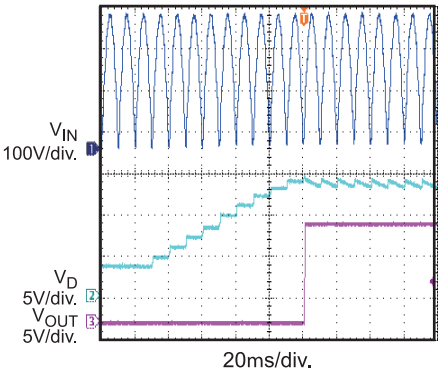
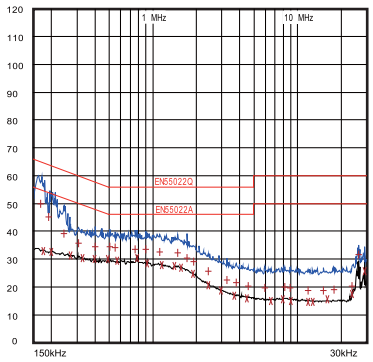
Thermal Shutdown Protection Recovery
V_{IN} = 115V_{AC}



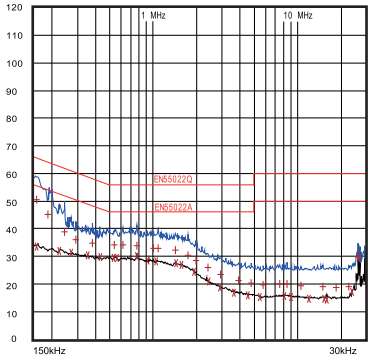
Thermal Shutdown Protection Recovery
V_{IN} =230V_{AC}



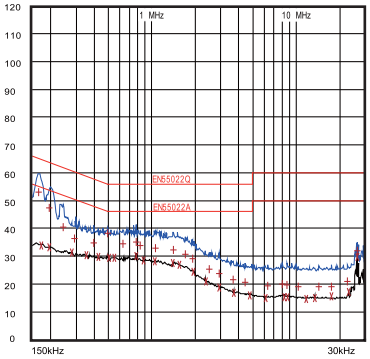
EMI Performance
115 L Line



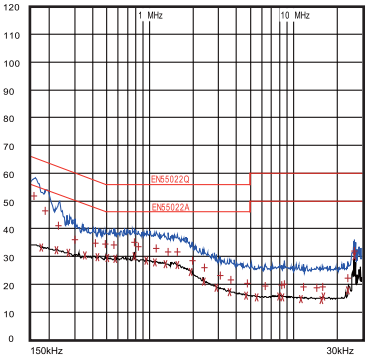
EMI Performance
115 N Line



EMI Performance
230 L Line



EMI Performance
230 N Line



PRINTED CIRCUIT BOARD LAYOUT

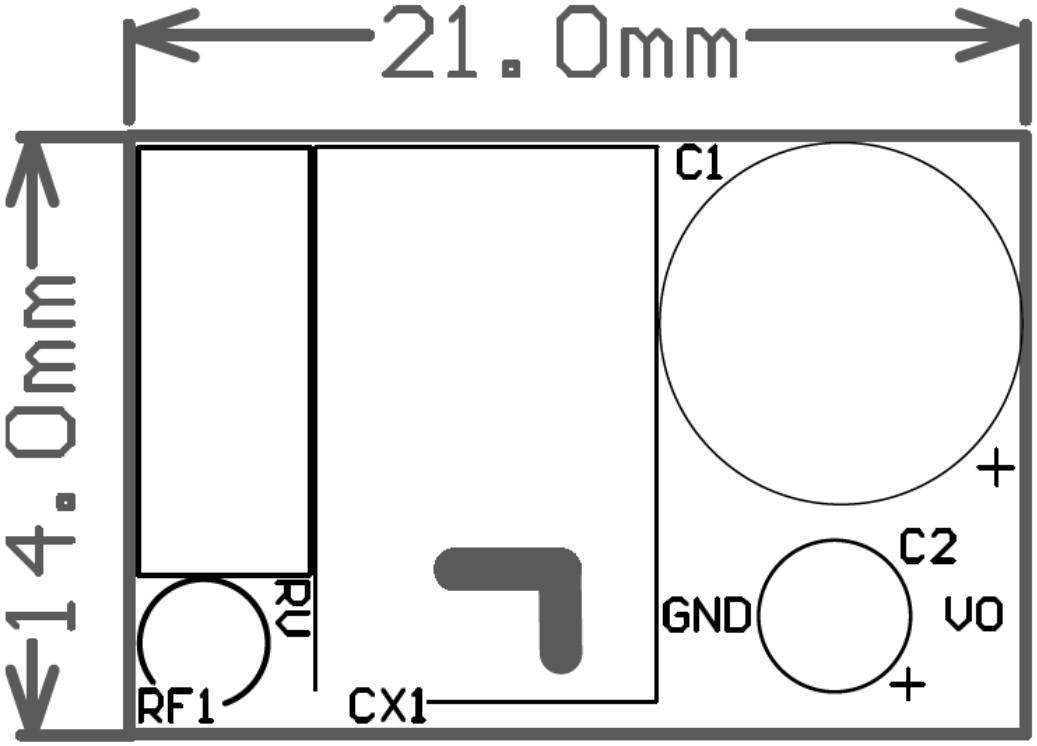


Figure 1 — Top Silk Layer

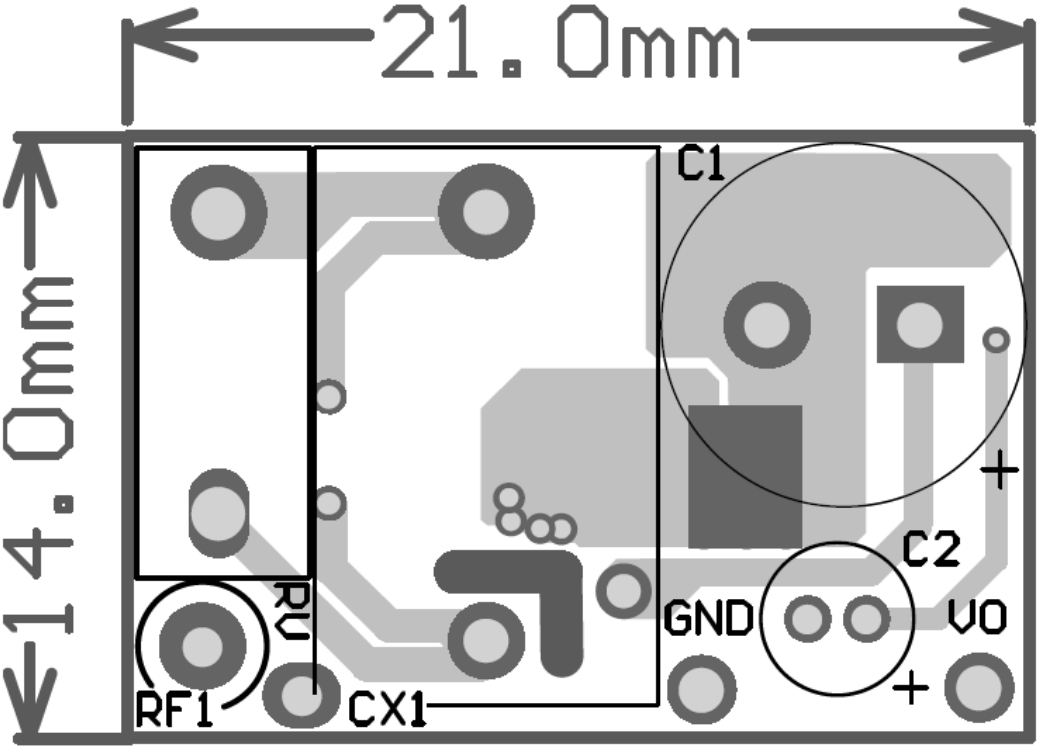


Figure 2 — Top Layer

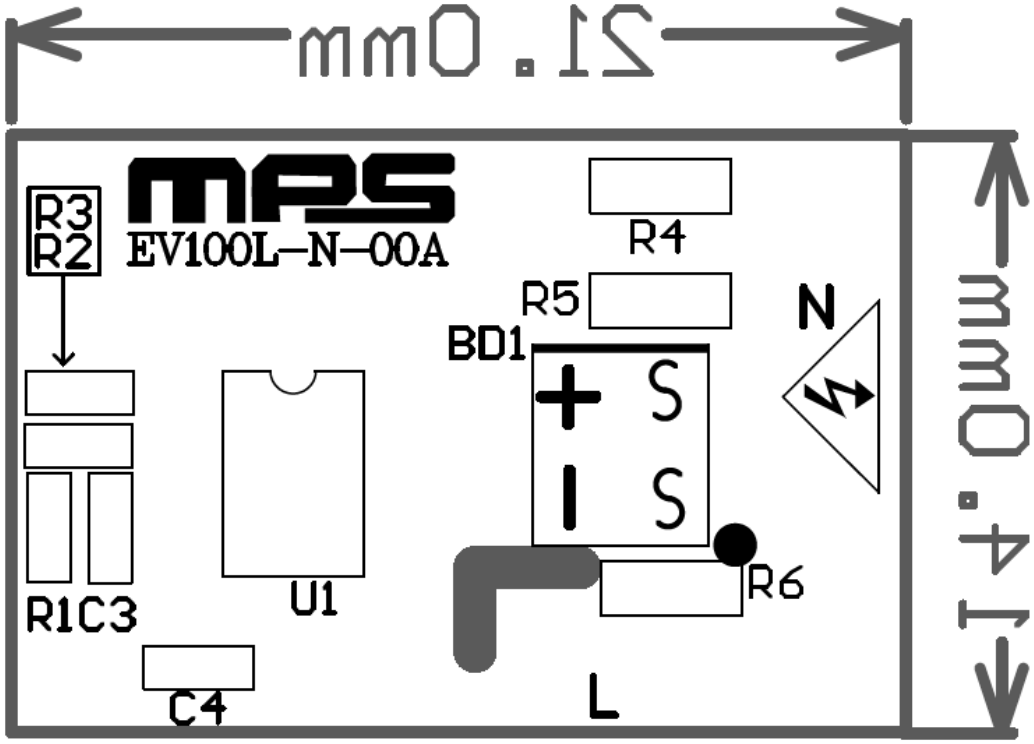


Figure 3 — Bottom Silk

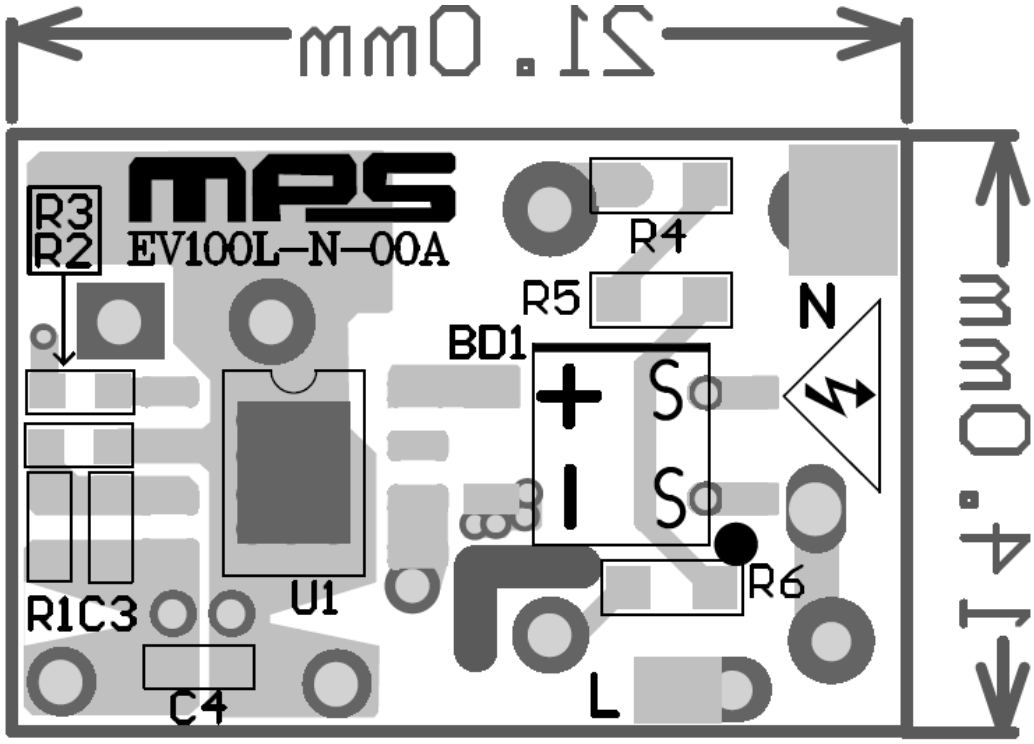


Figure 4 — Bottom Layer